

SANGDEST MICROELECTRONICS

MBRF2050/2060CT

Green Products

Technical Data Data Sheet N0075, Rev. A

Rev. A

MBRF2050/2060CT SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

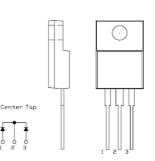
Features:

Ъ2

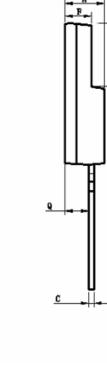
- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device

Mechanical Dimensions (In mm)

- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



OUTLINE DRAWING



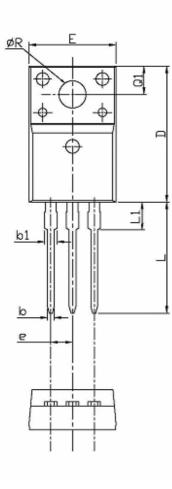
| | OPTION 1(CJ) | | OPTION 2(HD) | |
|-----|--------------|-------|--------------|-------|
| Dim | Min | Max | Min | Max |
| Α | 4.35 | 4.65 | 4.30 | 4.70 |
| b | 0.50 | 0.75 | 0.50 | 0.75 |
| b1 | 1.15 | 1.402 | 1.20 | 1.45 |
| b2 | 1.55 | 1.802 | 1.60 | 1.85 |
| b3 | 1.55 | 1.65 | 1.50 | 1.75 |
| b4 | 1.10 | 1.35 | 1.10 | 1.35 |
| С | 0.50 | 0.75 | 0.55 | 0.75 |
| D | 14.8 | 15.2 | 14.80 | 15.20 |
| Е | 10.06 | 10.26 | 9.96 | 10.36 |
| е | 2.46 | 2.62 | 2.55TYP | |
| F | 2.85 | 3.15 | 2.80 3.20 | |
| G | 6.50 | 6.90 | 6.50 | 6.90 |
| L | 12.70 | 13.70 | 12.70 | 13.70 |
| L1 | 3.40 | 3.80 | 3.40 | 4.00 |
| L2 | 2.60 | 3.00 | - | - |
| Q | 2.60 | 2.80 | 2.50 | 2.90 |
| Q1 | 2.50 | 2.90 | 2.50 | 2.90 |
| ØR | 3.40 | 3.60 | 3.30 | 3.70 |

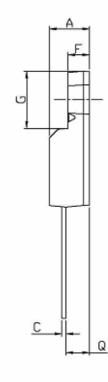
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| | OPTION 3 | | OPTION 4 | | |
|-----|----------|-------|----------|-------|--|
| Dim | Min | Мах | Min | Max | |
| Α | 4.53 | 4.93 | 4.50 | 4.90 | |
| b | 0.71 | 0.91 | 0.70 | 0.90 | |
| b1 | 1.15 | 1.39 | 1.33 | 1.47 | |
| С | 0.36 | 0.53 | 0.45 | 0.60 | |
| D | 15.67 | 16.07 | 15.67 | 16.07 | |
| E | 9.96 | 10.36 | 9.96 | 10.36 | |
| е | 2.54TYP | | 2.54 BSC | | |
| F | 2.34 | 2.76 | 2.34 | 2.74 | |
| G | 6.50 | 6.90 | 6.48 | 6.88 | |
| L | 12.37 | 12.77 | 12.78 | 13.18 | |
| L1 | 2.23 | 2.63 | 3.03 | 3.43 | |
| Q | 2.56 | 2.96 | 2.56 | 2.96 | |
| Q1 | 3.10 | 3.50 | 3.10 | 3.50 | |
| ØR | 2.98 | 3.38 | 3.08 | 3.28 | |



Where XXXXX is YYWWL

= Device Type

= Package type

= Configuration

= SSG = Year

= Week = Lot Number

= Forward Current (20A)

= Reverse Voltage (50/60V)

MBR

50/60

CT SSG

YY WW

L

F 20

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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

| Device | Package | Shipping |
|------------|-----------|--------------|
| MBRF2050CT | ITO-220AB | 50pcs / tube |
| MBRF2060CT | (Pb-Free) | |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

| Characteristics | Symbol | Condition | | Max. | Units |
|---|------------------|--|----|------------|-------|
| Peak Inverse Voltage | V _{RWM} | - | 50 | MBRF2050CT | V |
| | V RWM | | 60 | MBRF2060CT | |
| Average Rectified Output Current | Ιo | 50Hz Full Sine Wave Resistive Load @T _c = 80 ℃ | | 20 | А |
| Max. Peak One Cycle Non- Repetitive Surge Current (per leg) | I _{FSM} | 50Hz Full Sine Wave | | 150 | А |

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Electrical Characteristics:

| Characteristics | Symbol | Condition | Max. | Units |
|--|-----------------|---|--------|-------|
| Max. Forward Voltage Drop (per leg) * | V _{F1} | @ 10A, Pulse, T _J = 25 °C | 0.80 | V |
| Max. Reverse Current (per leg) * | I _{R1} | $@V_R = rated V_R Pulse$ T _J = 25 °C | 1.0 | mA |
| Max. Junction Capacitance (per leg) | C _T | @V _R = 4V, T _C = 25 °C f _{SIG} = 1MHz | 400 | pF |
| Max. Voltage Rate of Change | dv/dt | - | 10,000 | V/µs |

* Pulse Width < 300µs, Duty Cycle <2%

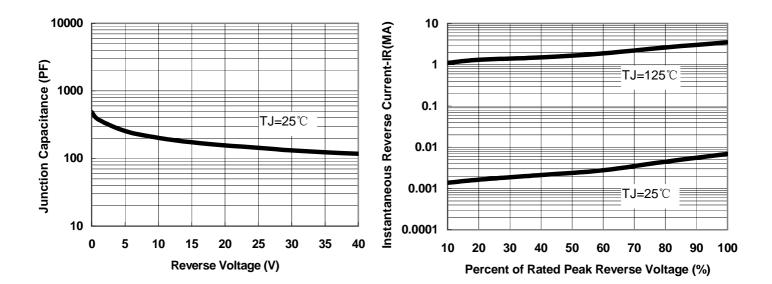
Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|---------------------|---|---------------|-------|
| Junction Temperature Range | TJ | - | -55 to +150 | °C |
| Storage Temperature Range | T _{stg} | - | -55 to +150 | °C |
| Maximum Thermal Resistance Junction to Case | $R_{	ext{	hetaJC}}$ | DC operation | 2.3 | °C/W |
| Typical Thermal Resistance Case to Heat Sink | R _{θCS} | Mounting surface, smooth and greased (only for ITO-220) | 0.50 | °C/W |
| Approximate Weight | wt | - | 2 | g |
| Case Style | ITO-220AB | | | |

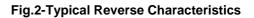


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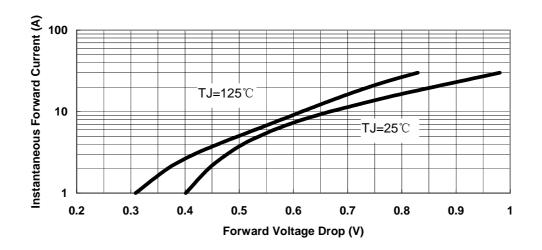


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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